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October 2013

FQT3P20

P-Channel QFET® MOSFET

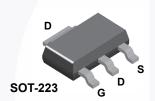
-200 V, -0.67 A, 2.7 Ω

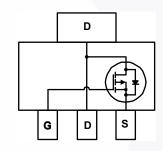
Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- -0.67 A, -200 V, $R_{DS(on)}$ = 2.7 Ω (Max.) @ V_{GS} = 10 V, I_D = 0.335 A
- Low Gate Charge (Typ. 6.0 nC)
- Low Crss (Typ. 7.5 pF)





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQT3P20TF	Unit	
V_{DSS}	Drain-Source Voltage		-200	V	
I _D	Drain Current - Continuous (T _C = 25°	C)	-0.67	А	
	- Continuous (T _C = 70°C	C)	-0.53	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	-2.7	А	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	150	mJ	
I _{AR}	Avalanche Current	(Note 1)	-0.67	Α	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	0.25	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-5.5	V/ns	
P_{D}	Power Dissipation (T _C = 25°C)		2.5	W	
	- Derate above 25°C		0.02	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T _L	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FQT3P20TF	Unit	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	50	°C/W	

Device Marking	Device	Package Reel Size		Tape Width	Quantity	
FQT3P20	FQT3P20TF	SOT-223	13"	12 mm	2500 units	

Flectrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	-200			V
$\Delta B_{VDSS}/$ ΔT_{J}	Breakdown Voltage Temperature Coefficient	I _D = -250 μA, Referenced to 25°C		-0.18		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -200 V, V _{GS} = 0 V			-1	μΑ
		V _{DS} = -160 V, T _C = 125°C			-10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = 30 V, V _{DS} = 0 V	1		100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-3.0		-5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = -10 V, I _D = -0.335 A		2.06	2.7	Ω
g _{FS}	Forward Transconductance	V _{DS} = -40 V, I _D = -0.335 A		0.7		S
Dynam C _{iss}	ic Characteristics Input Capacitance	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V},$		190	250	pF
C _{oss}	Output Capacitance	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1.0 \text{ MHz}$		45	60	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1.0 WH12		7.5	10	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = -100 V, I _D = -2.8 A,		8.5	25	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		35	80	ns
t _{d(off)}	Turn-Off Delay Time			12	35	ns
t _f	Turn-Off Fall Time	(Note 4)		25	60	ns
Qg	Total Gate Charge	$V_{DS} = -160 \text{ V}, I_{D} = -2.8 \text{ A},$		6.0	8.0	nC
Q_{gs}	Gate-Source Charge	V _{GS} = -10 V		1.7		nC
Q_{gd}	Gate-Drain Charge	(Note 4)		2.9		nC
Drain-S	Source Diode Characteristics ar	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				-0.67	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				-2.7	Α

 V_{SD}

trr

Qrr

Notes:
1. Repetitive Rating : Pulse width limited by maximum junction temperature
2. L = 500mH, I_{AS} = -0.67A, V_{DD} = -50V, R_G = 25 Ω , Starting T_J = 25°C
3. I_{SD} \leq -2.8A, di/dt \leq 300A/µs, V_{DD} \leq BV_{DSS}, Starting T_J = 25°C
4. Essentially independent of operating temperature

Drain-Source Diode Forward Voltage

Reverse Recovery Time

Reverse Recovery Charge

V

ns

μC

-5.0

100

0.34

 $V_{GS} = 0 \overline{V, I_S = -0.67 A}$

 $V_{GS} = 0 \text{ V}, I_{S} = -2.8 \text{ A},$

 $dI_F / dt = 100 A/\mu s$

Typical Characteristics

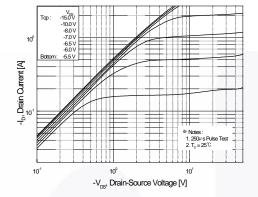


Figure 1. On-Region Characteristics

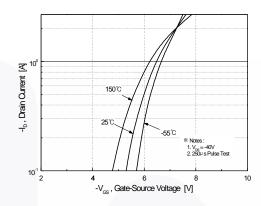


Figure 2. Transfer Characteristics

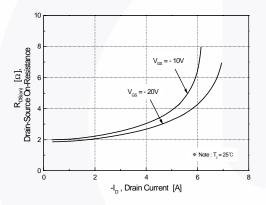


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

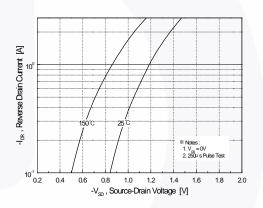


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

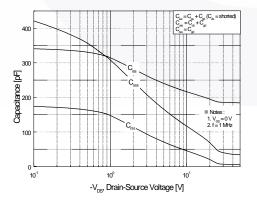


Figure 5. Capacitance Characteristics

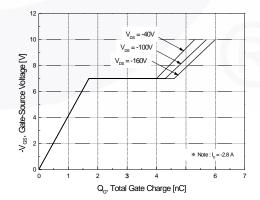


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

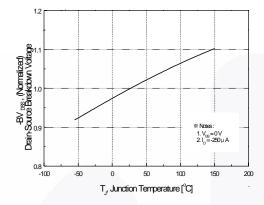


Figure 7. Breakdown Voltage Variation vs. Temperature

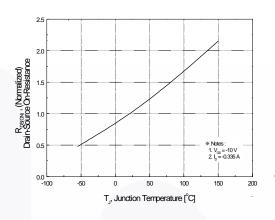


Figure 8. On-Resistance Variation vs. Temperature

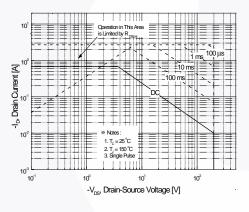


Figure 9. Maximum Safe Operating Area

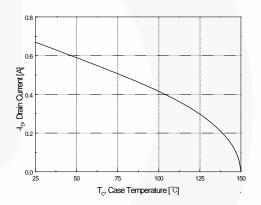


Figure 10. Maximum Drain Current vs. Case Temperature

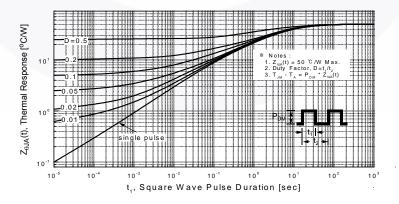


Figure 11. Transient Thermal Response Curve



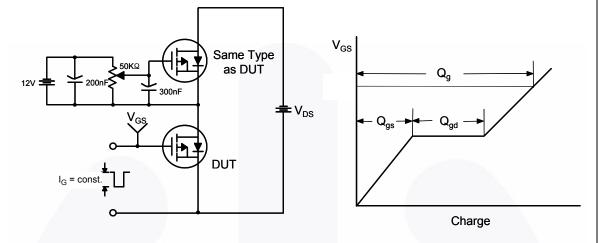


Figure 13. Resistive Switching Test Circuit & Waveforms

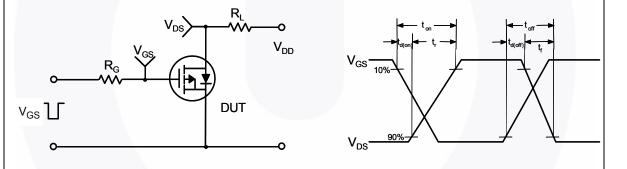


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

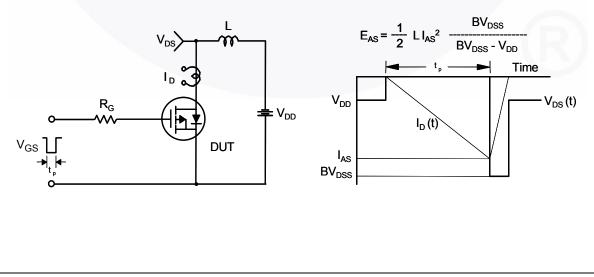


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms I_{SD} Driver Compliment of DUT ‡ VDD (N-Channel) $\prod V_{GS}$ \bullet dv/dt controlled by $R_{\rm G}$ \bullet I_{SD} controlled by pulse period Gate Pulse Width V_{GS} Gate Pulse Period 10V (Driver) **Body Diode Reverse Current** I_{SD} (DUT) di/dt I_{FM} , Body Diode Forward Current V_{DS} V_{SD} (DUT) Body Diode Forward Voltage Drop Body Diode Recovery dv/dt

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Mechanical Dimensions

SOT-223 4L

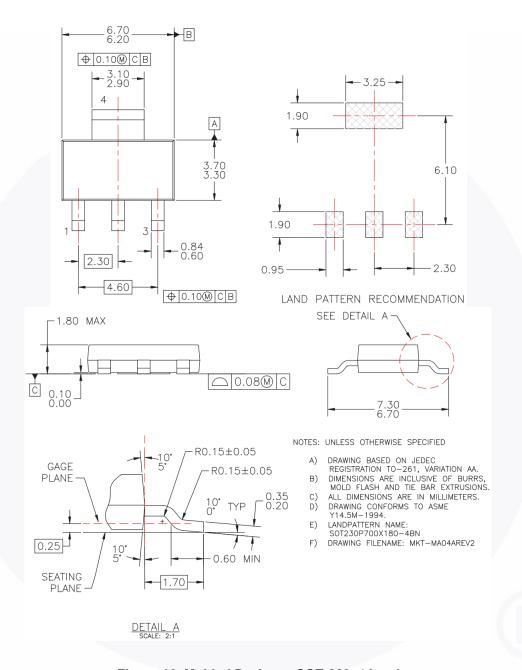


Figure 16. Molded Package, SOT-223, 4 Lead

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Dimension in Millimeters





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